imall

Chipsmall Limited consists of a professional team with an average of over 10 year of expertise in the distribution of electronic components. Based in Hongkong, we have already established firm and mutual-benefit business relationships with customers from, Europe, America and south Asia, supplying obsolete and hard-to-find components to meet their specific needs.

With the principle of "Quality Parts, Customers Priority, Honest Operation, and Considerate Service", our business mainly focus on the distribution of electronic components. Line cards we deal with include Microchip, ALPS, ROHM, Xilinx, Pulse, ON, Everlight and Freescale. Main products comprise IC, Modules, Potentiometer, IC Socket, Relay, Connector. Our parts cover such applications as commercial, industrial, and automotives areas.

We are looking forward to setting up business relationship with you and hope to provide you with the best service and solution. Let us make a better world for our industry!



Contact us

Tel: +86-755-8981 8866 Fax: +86-755-8427 6832 Email & Skype: info@chipsmall.com Web: www.chipsmall.com Address: A1208, Overseas Decoration Building, #122 Zhenhua RD., Futian, Shenzhen, China





UMX-630-D16-G

ULTRA-LOW NOISE COAXIAL RESONATOR OSCILLATORS

Package: D16, 12.7mm x 12.7mm x 5.6mm

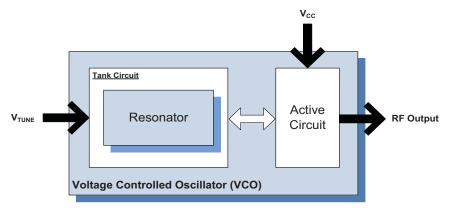


Features

- Ultra-Linear Tuning / Ultra-Low Phase Noise
- Frequency: 2400 MHz to 2600 MHz
- Resonator: Ceramic
- PCB: Rogers
- Package Size: 12.7mm x 12.7mm x 5.6mm (0.5in x 0.5in x 0.22in)

Applications

- Point-to-Point Radio
- DRO/YIG Multiplied Replacements
- Low Phase Noise Applications
- SAW VCO Replacement



Functional Block Diagram

Product Description

This VCO series features ultra-low phase noise, lower phase transients, lower harmonics, and lower pushing and pulling without any performance penalties typically associated with high technology designs.

Ordering Information

UMX-630-D16-G Contact us at 1-480-756-6070

Optimum Technology Matching® Applied

🗌 GaAs HBT	SiGe BiCMOS	🗌 GaAs pHEMT
GaAs MESFET	Si BiCMOS	□_Si CMOS
InGaP HBT	SiGe HBT	🗹 Si BJT

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GaN HEMT BiFET HBT LDMOS

UMX-630-D16-G



Absolute Maximum Ratings

Parameter	Rating	Unit
Operating Ambient Temperature[1]	-40 to +85	°C
Storage Temperature	-55 to +125	°C

[1] Frequency drift: 6MHz typical (either extreme).



Caution! ESD sensitive device.

Exceeding any one or a combination of the Absolute Maximum Rating conditions may cause permanent damage to the device. Extended application of Absolute Maximum Rating conditions to the device may reduce device reliability. Specified typical performance or functional operation of the device under Absolute Maximum Rating conditions is not implied.

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RoHS (Restriction of Hazardous Substances): Compliant per EU Directive 2002/95/EC.

Parameter		Specification		11	
	Min.	Тур.	Max.	Unit	Condition
Overall					
Frequency Range	2400		2600	MHz	
Tuning Voltage	1		12	V _{DC}	
Tuning Sensitivity		20		MHz/V	
Output Power	5	7	9	dBm	
	5			dBm	At V _T =0
Output Phase Noise		-82	-77	dBc/Hz	1kHz
		-108	-105	dBc/Hz	10kHz
		-130	-127	dBc/Hz	100 kHz
		-152	-147	dBc/Hz	1000 kHz
		-164	-159	dBc/Hz	10000 kHz
Second Harmonic		-15	-10	dBc	
Frequency Pulling		0.5	1	MHz p-p	At 12dBr, all phases
Tuning Port Capacitance		28		pF	
Modulation Bandwidth		1000		kHz	3dB BW
Frequency Pushing		0.5	1.5	MHz/V	
Power Supply					
Operating Voltage		8		V	
Supply Current		28		mA	





Package Drawing & Pin Outs

12.7mm x 12.7mm x 5.6mm (0.5in x 0.5in x 0.22in)

